

COMLINEAR[®] CLC1050, CLC2050, CLC4050

Low Power, 3V to 36V, Single, Dual, Quad Amplifiers

COMLINEAR CLC1050, CLC2050, CLC4050 Low Power, 3V to 36V, Single, Dual, Quad Amplifiers Rev 1A

FEATURES

- Unity gain stable
- 100dB voltage gain
- 550kHz unity gain bandwidth
- 0.5mA supply current
- 20nA input bias current
- 2mV input offset voltage
- 3V to 36V single supply voltage range
- ±1.5V to ±18V dual supply voltage range
- Input common mode voltage range includes ground
- 0V to $V_S - 1.5V$ output voltage swing
- CLC2050: improved replacement for industry standard LM358
- CLC4050: Improved replacement for industry standard LM324
- CLC1050: Pb-free SOT23-5
- CLC2050: Pb-free SOIC-8
- CLC4050: Pb-free SOIC-14

APPLICATIONS

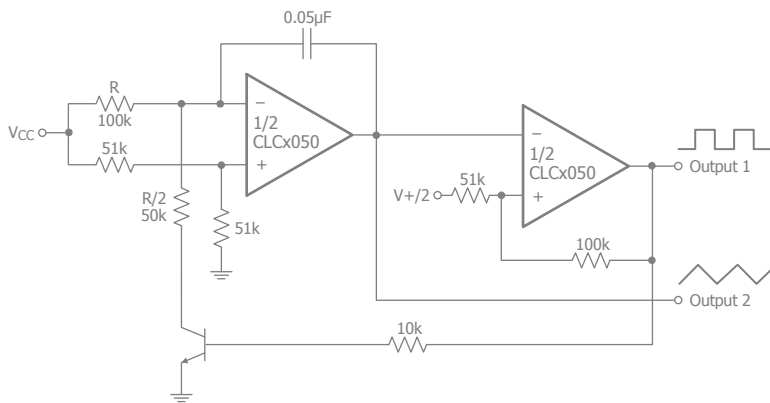
- Battery Charger
- Active Filters
- Transducer amplifiers
- General purpose controllers
- General purpose instruments

General Description

The COMLINEAR CLC1050 (single), CLC2050 (dual), and CLC4050 (quad) are voltage feedback amplifiers that are internally frequency compensated to provide unity gain stability. At unity gain ($G=1$), these amplifiers offer 550kHz of bandwidth. They consume only 0.5mA of supply current over the entire power supply operating range. The CLC1050, CLC2050, and CLC4050 are specifically designed to operate from single or dual supply voltages.

The COMLINEAR CLC1050, CLC2050, and CLC4050 offer a common mode voltage range that includes ground and a wide output voltage swing. The combination of low-power, high supply voltage range, and low supply current make these amplifiers well suited for many general purpose applications and as alternatives to several industry standard amplifiers on the market today.

Typical Application - Voltage Controlled Oscillator (VCO)



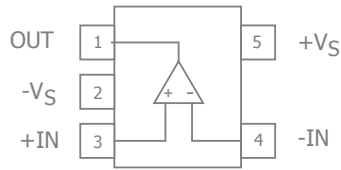
Ordering Information

| Part Number | Package | Pb-Free | RoHS Compliant | Operating Temperature Range | Packaging Method |
|---------------|---------|---------|----------------|-----------------------------|------------------|
| CLC1050IST5X | SOT23-5 | Yes | Yes | -40°C to +85°C | Reel |
| CLC2050ISO8X | SOIC-8 | Yes | Yes | -40°C to +85°C | Reel |
| CLC4050ISO14X | SOIC-14 | Yes | Yes | -40°C to +85°C | Reel |

Moisture sensitivity level for all parts is MSL-1.



CLC1050 Pin Configuration



CLC1050 Pin Assignments

| Pin No. | Pin Name | Description |
|---------|----------|-----------------|
| 1 | OUT | Output |
| 2 | -VS | Negative supply |
| 3 | +IN | Positive input |
| 4 | -IN | Negative input |
| 5 | +VS | Positive supply |

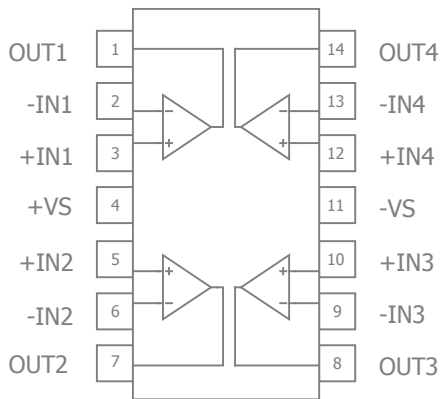
CLC2050 Pin Configuration



CLC2050 Pin Configuration

| Pin No. | Pin Name | Description |
|---------|----------|---------------------------|
| 1 | OUT1 | Output, channel 1 |
| 2 | -IN1 | Negative input, channel 1 |
| 3 | +IN1 | Positive input, channel 1 |
| 4 | -VS | Negative supply |
| 5 | +IN2 | Positive input, channel 2 |
| 6 | -IN2 | Negative input, channel 2 |
| 7 | OUT2 | Output, channel 2 |
| 8 | +VS | Positive supply |

CLC4050 Pin Configuration



CLC4050 Pin Configuration

| Pin No. | Pin Name | Description |
|---------|----------|---------------------------|
| 1 | OUT1 | Output, channel 1 |
| 2 | -IN1 | Negative input, channel 1 |
| 3 | +IN1 | Positive input, channel 1 |
| 4 | +VS | Positive supply |
| 5 | +IN2 | Positive input, channel 2 |
| 6 | -IN2 | Negative input, channel 2 |
| 7 | OUT2 | Output, channel 2 |
| 8 | OUT3 | Output, channel 3 |
| 9 | -IN3 | Negative input, channel 3 |
| 10 | +IN3 | Positive input, channel 3 |
| 11 | -VS | Negative supply |
| 12 | +IN4 | Positive input, channel 4 |
| 13 | -IN4 | Negative input, channel 4 |
| 14 | OUT4 | Output, channel 4 |



Absolute Maximum Ratings

The safety of the device is not guaranteed when it is operated above the "Absolute Maximum Ratings". The device should not be operated at these "absolute" limits. Adhere to the "Recommended Operating Conditions" for proper device function. The information contained in the Electrical Characteristics tables and Typical Performance plots reflect the operating conditions noted on the tables and plots.

| Parameter | Min | Max | Unit |
|--|------|-----|------|
| Supply Voltage | 0 | 40 | V |
| Differential Input Voltage | | 40 | V |
| Input Voltage | -0.3 | 40 | V |
| Power Dissipation ($T_A = 25^\circ\text{C}$) - SOIC-8 | | 550 | mW |
| Power Dissipation ($T_A = 25^\circ\text{C}$) - SOIC-14 | | 800 | mW |

Reliability Information

| Parameter | Min | Typ | Max | Unit |
|-----------------------------------|-----|-----|-----|---------------------------|
| Junction Temperature | | | 150 | $^\circ\text{C}$ |
| Storage Temperature Range | -65 | | 150 | $^\circ\text{C}$ |
| Lead Temperature (Soldering, 10s) | | | 260 | $^\circ\text{C}$ |
| Package Thermal Resistance | | | | |
| SOT23-5 | | 221 | | $^\circ\text{C}/\text{W}$ |
| SOIC-8 | | 100 | | $^\circ\text{C}/\text{W}$ |
| SOIC-14 | | 88 | | $^\circ\text{C}/\text{W}$ |

Notes:

Package thermal resistance (θ_{JA}), JEDEC standard, multi-layer test boards, still air.

Recommended Operating Conditions

| Parameter | Min | Typ | Max | Unit |
|-----------------------------|-----------------|-----|-----------------|------------------|
| Operating Temperature Range | -40 | | +85 | $^\circ\text{C}$ |
| Supply Voltage Range | 3 (± 1.5) | | 36 (± 18) | V |



Electrical Characteristics

$T_A = 25^\circ\text{C}$ (if **bold**, $T_A = -40$ to $+85^\circ\text{C}$), $V_S = +5\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$ to $V_S/2$, $G = 2$; unless otherwise noted.

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---------------------------|---|---|-----------|-------------|--------------|------------------------------|
| Frequency Domain Response | | | | | | |
| UGBW _{SS} | Unity Gain Bandwidth | $G = +1, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 5\text{V}$ | | 330 | | kHz |
| | | $G = +1, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 30\text{V}$ | | 550 | | kHz |
| BW _{SS} | -3dB Bandwidth | $G = +2, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 5\text{V}$ | | 300 | | kHz |
| | | $G = +1, V_{\text{OUT}} = 0.2V_{\text{pp}}, V_S = 30\text{V}$ | | 422 | | kHz |
| BW _{LS} | Large Signal Bandwidth | $G = +2, V_{\text{OUT}} = 1V_{\text{pp}}, V_S = 5\text{V}$ | | 107 | | kHz |
| | | $G = +2, V_{\text{OUT}} = 2V_{\text{pp}}, V_S = 30\text{V}$ | | 76 | | kHz |
| Time Domain Response | | | | | | |
| t_r, t_f | Rise and Fall Time | $V_{\text{OUT}} = 1\text{V}$ step; (10% to 90%), $V_S = 5\text{V}$ | | 4 | | μs |
| | | $V_{\text{OUT}} = 2\text{V}$ step; (10% to 90%), $V_S = 30\text{V}$ | | 5.6 | | μs |
| OS | Overshoot | $V_{\text{OUT}} = 0.2\text{V}$ step | | 1 | | % |
| SR | Slew Rate | 1V step, $V_S = 5\text{V}$ | | 200 | | V/ms |
| | | 4V step, $V_S = 30\text{V}$ | | 285 | | V/ms |
| Distortion/Noise Response | | | | | | |
| THD | Total Harmonic Distortion | $V_{\text{OUT}} = 2V_{\text{pp}}, f = 1\text{kHz}, G = 20\text{dB}, C_L = 100\text{pF}, V_S = 30\text{V}$ | | 0.015 | | % |
| e_n | Input Voltage Noise | $> 10\text{kHz}, V_S = 5\text{V}$ | | 45 | | nV/ $\sqrt{\text{Hz}}$ |
| | | $> 10\text{kHz}, V_S = 30\text{V}$ | | 40 | | nV/ $\sqrt{\text{Hz}}$ |
| X_{TALK} | Crosstalk | Channel-to-channel, 1kHz to 20kHz | | 120 | | dB |
| DC Performance | | | | | | |
| V_{IO} | Input Offset Voltage ⁽¹⁾ | $V_{\text{OUT}} = 1.4\text{V}, R_S = 0\Omega, V_S = 5\text{V}$ to 30V | | 2 | 5 | mV |
| | | | | | 7 | mV |
| dV_{IO} | Average Drift | | | 7 | | $\mu\text{V}/^\circ\text{C}$ |
| I_b | Input Bias Current ⁽¹⁾ | $V_{\text{CM}} = 0\text{V}$ | | 20 | 100 | nA |
| | | | | | 200 | nA |
| I_{OS} | Input Offset Current ⁽¹⁾ | $V_{\text{CM}} = 0\text{V}$ | | 5 | 30 | nA |
| | | | | | 100 | nA |
| PSRR | Power Supply Rejection Ratio ⁽¹⁾ | DC, $V_S = 5\text{V}$ to 30V | 70 | 100 | | dB |
| | | | 60 | | | dB |
| A_{OL} | Open-Loop Gain ⁽¹⁾ | $+V_S = 15\text{V}, R_L = \geq 2\text{k}\Omega, V_{\text{OUT}} = 1\text{V}$ to 11V | 85 | 100 | | dB |
| | | | 80 | | | dB |
| I_S | Supply Current, CLC1050 ⁽¹⁾ | $R_L = \infty, V_S = 30\text{V}$ | | 0.65 | 1.5 | mA |
| | | $R_L = \infty, V_S = 5\text{V}$ | | 0.45 | 1.0 | mA |
| | Supply Current, CLC2050 ⁽¹⁾ | $R_L = \infty, V_S = 30\text{V}$ | | 0.7 | 2.0 | mA |
| | | $R_L = \infty, V_S = 5\text{V}$ | | 0.5 | 1.2 | mA |
| | Supply Current, CLC4050 ⁽¹⁾ | $R_L = \infty, V_S = 30\text{V}$ | | 1.0 | 3.0 | mA |
| | | $R_L = \infty, V_S = 5\text{V}$ | | 0.7 | 1.2 | mA |
| Input Characteristics | | | | | | |
| CMIR | Common Mode Input Range ^(1,3) | $+V_S = 30\text{V}$ | 0 | | $+V_S - 1.5$ | V |
| CMRR | Common Mode Rejection Ratio ⁽¹⁾ | DC, $V_{\text{CM}} = 0\text{V}$ to $(+V_S - 1.5\text{V})$ | 60 | 70 | | dB |
| | | | 60 | | | dB |
| Output Characteristics | | | | | | |
| V_{OH} | Output Voltage Swing, High ⁽¹⁾ | $+V_S = 30\text{V}, R_L = 2\text{k}\Omega$ | 26 | | | V |
| | | | 26 | | | V |
| | | $+V_S = 30\text{V}, R_L = 10\text{k}\Omega$ | 27 | 28 | | V |
| | | | 27 | | | V |



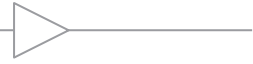
Electrical Characteristics continued

$T_A = 25^\circ\text{C}$ (if **bold**, $T_A = -40$ to $+85^\circ\text{C}$), $V_S = +5\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$ to $V_S/2$, $G = 2$; unless otherwise noted.

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|--------------|---|---|-----------|-----|-----------|---------------|
| V_{OL} | Output Voltage Swing, Low ⁽¹⁾ | $+V_S = 5\text{V}$, $R_L = 10\text{k}\Omega$ | | 5 | 20 | mV |
| | | | | | 30 | mV |
| I_{SOURCE} | Output Current, Sourcing ⁽¹⁾ | $V_{IN+} = 1\text{V}$, $V_{IN-} = 0\text{V}$, $+V_S = 15\text{V}$, $V_{OUT} = 2\text{V}$ | 20 | 40 | | mA |
| | | | 20 | | | |
| I_{SINK} | Output Current, Sinking ⁽¹⁾ | $V_{IN+} = 0\text{V}$, $V_{IN-} = 1\text{V}$, $+V_S = 15\text{V}$, $V_{OUT} = 2\text{V}$ | 10 | 15 | | mA |
| | | | 5 | | | |
| | | $V_{IN+} = 0\text{V}$, $V_{IN-} = 1\text{V}$, $+V_S = 15\text{V}$, $V_{OUT} = 0.2\text{V}$ | 12 | 50 | | μA |
| I_{SC} | Short Circuit Output Current ⁽¹⁾ | $+V_S = 15\text{V}$ | | 40 | 60 | mA |

Notes:

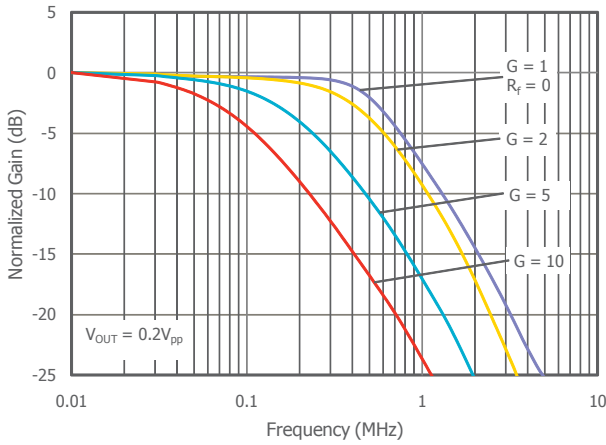
- 100% tested at 25°C . (Limits over the full temperature range are guaranteed by design.)
- The input common mode voltage of either input signal voltage should be kept $> 0.3\text{V}$ at 25°C . The upper end of the common-mode voltage range is $+V_S - 1.5\text{V}$ at 25°C , but either or both inputs can go to $+36\text{V}$ without damages, independent of the magnitude of V_S .



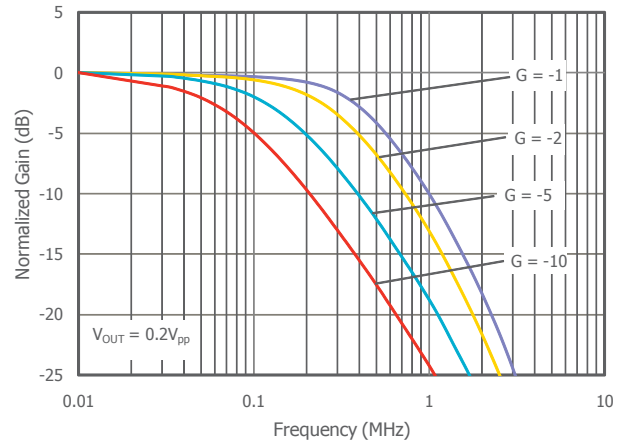
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

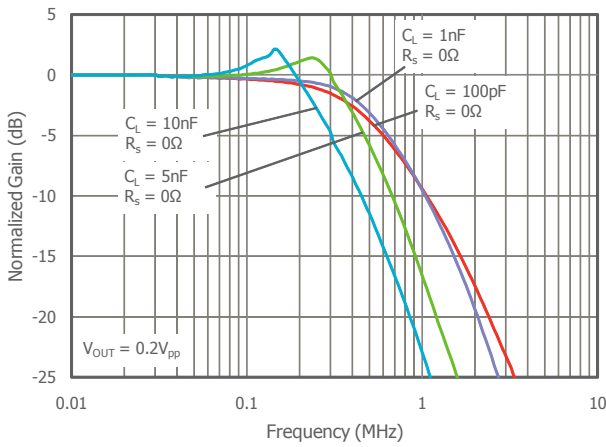
Non-Inverting Frequency Response



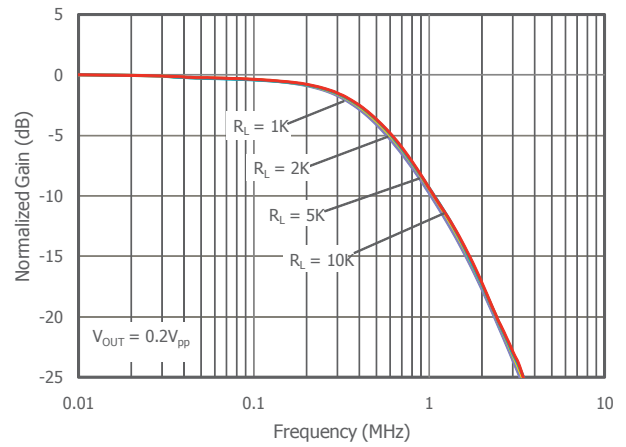
Inverting Frequency Response



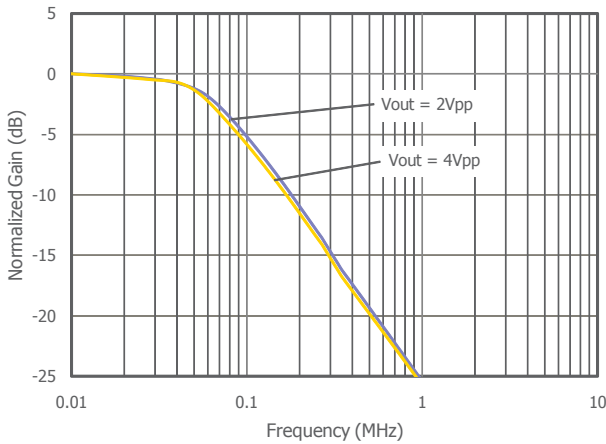
Frequency Response vs. C_L



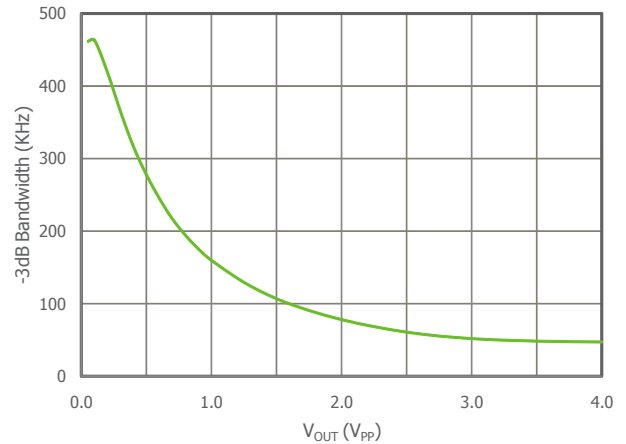
Frequency Response vs. R_L



Frequency Response vs. V_{OUT}



-3dB Bandwidth vs. V_{OUT}



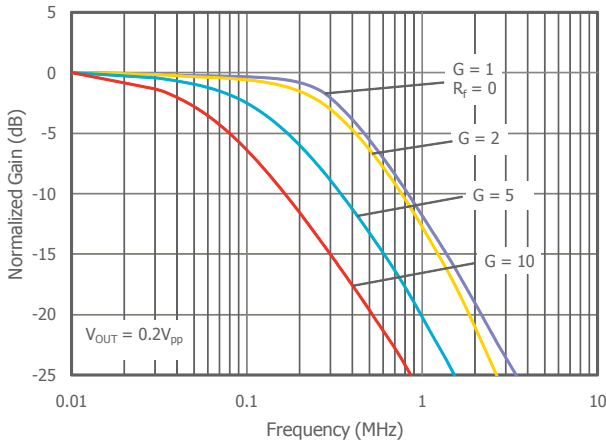
COMLINEAR CLC1050, CLC2050, CLC4050 Low Power, 3V to 36V, Single, Dual, Quad Amplifiers Rev 1A



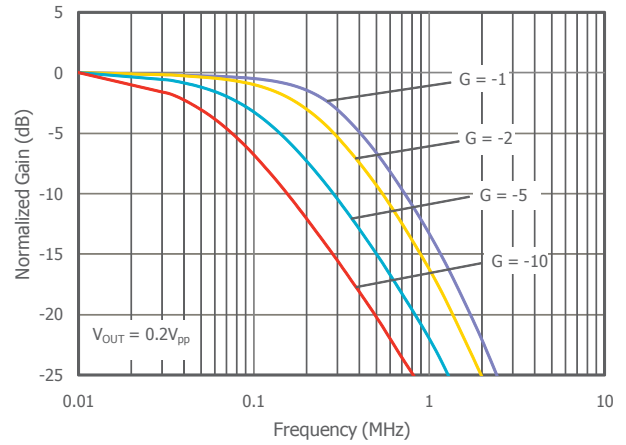
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

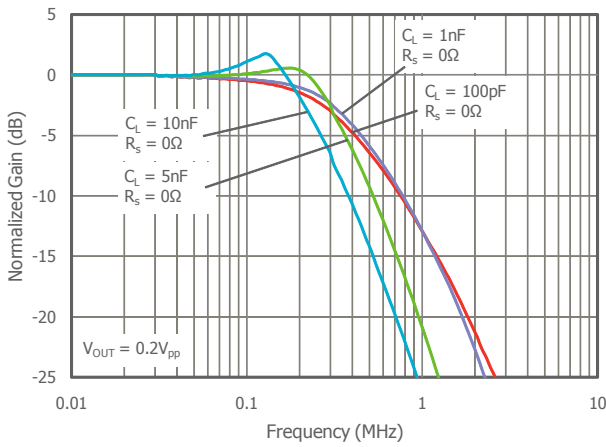
Non-Inverting Frequency Response at $V_S = 5\text{V}$



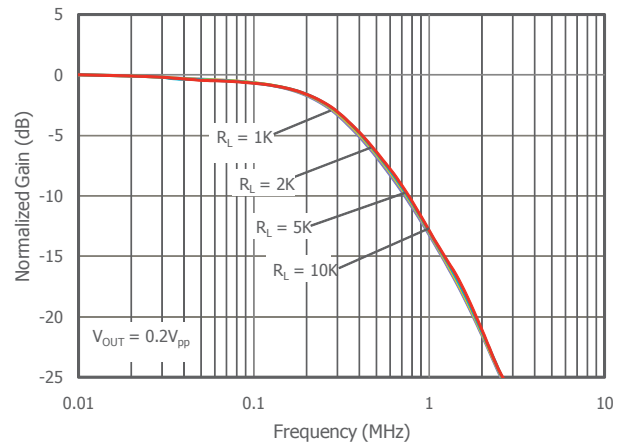
Inverting Frequency Response at $V_S = 5\text{V}$



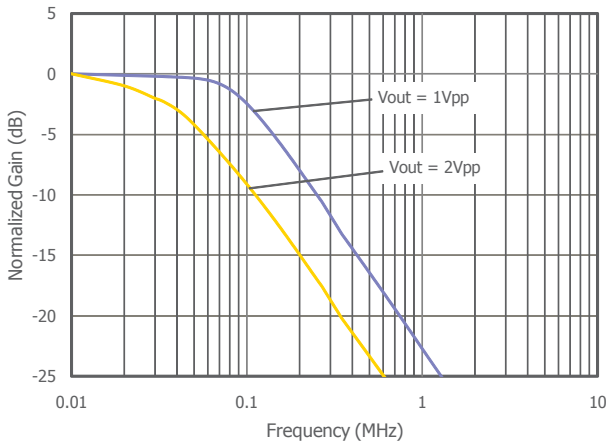
Frequency Response vs. C_L at $V_S = 5\text{V}$



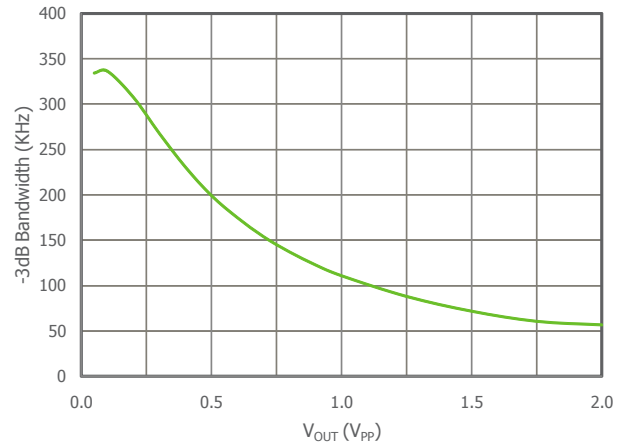
Frequency Response vs. R_L at $V_S = 5\text{V}$



Frequency Response vs. V_{OUT} at $V_S = 5\text{V}$



-3dB Bandwidth vs. V_{OUT} at $V_S = 5\text{V}$

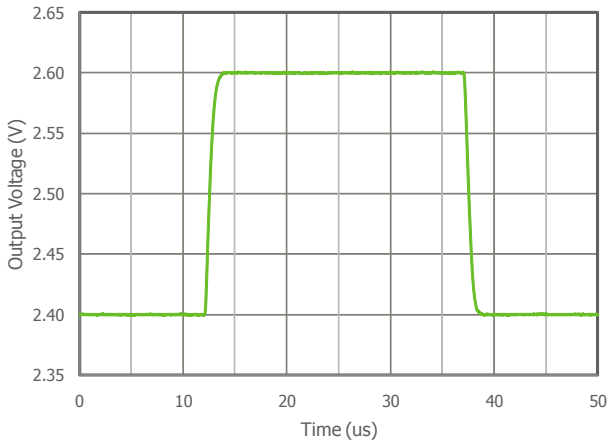




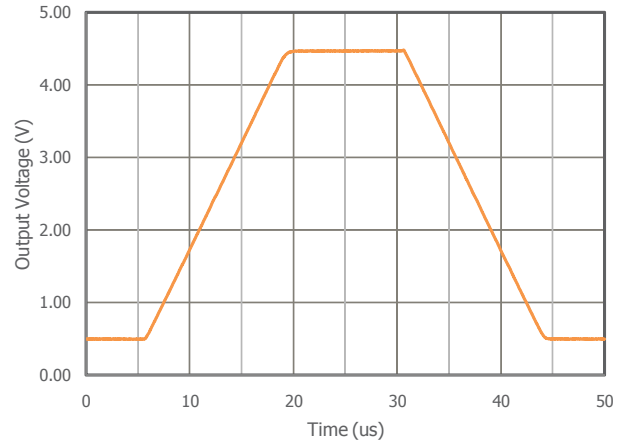
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

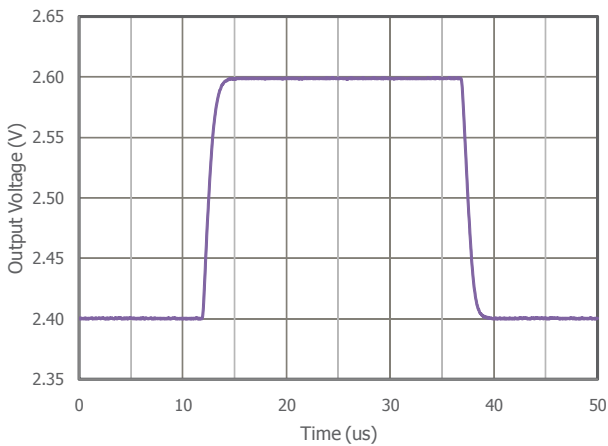
Small Signal Pulse Response



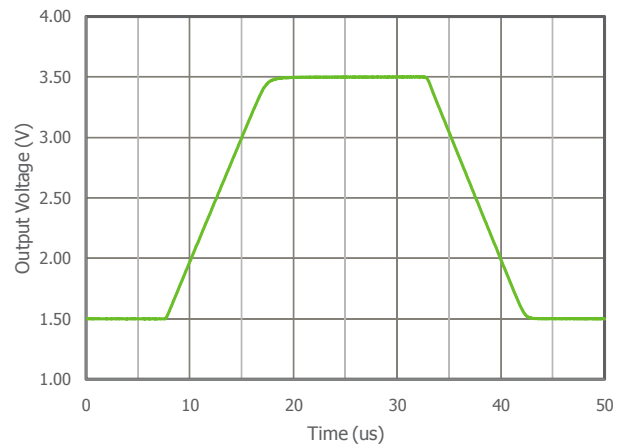
Large Signal Pulse Response



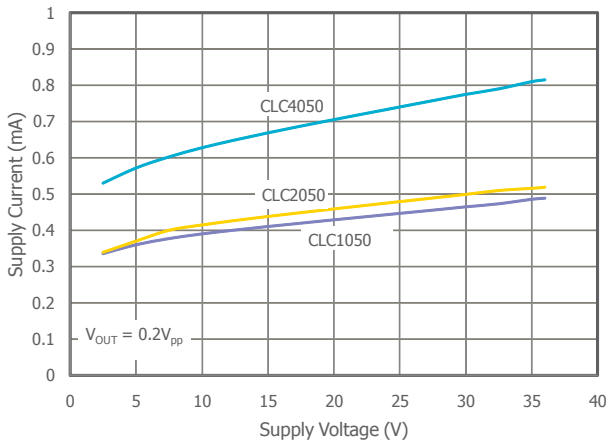
Small Signal Pulse Response at $V_S = 5\text{V}$



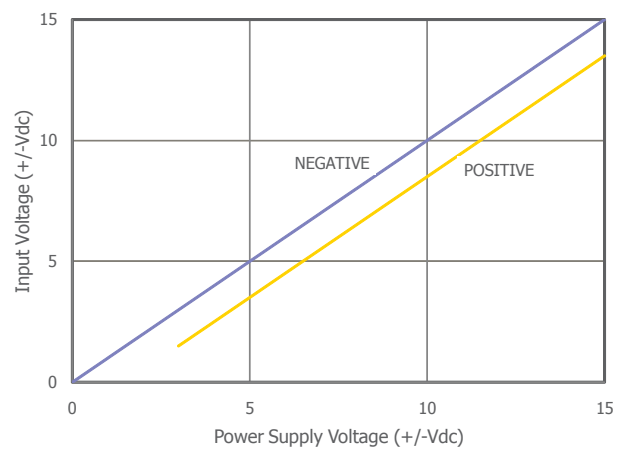
Large Signal Pulse Response at $V_S = 5\text{V}$



Supply Current vs. Supply Voltage



Input Voltage Range vs. Power Supply

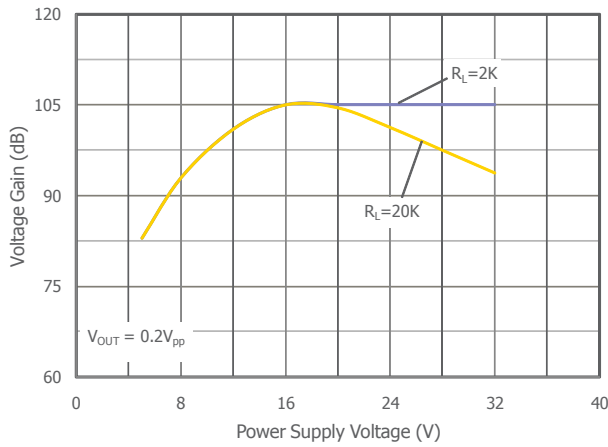




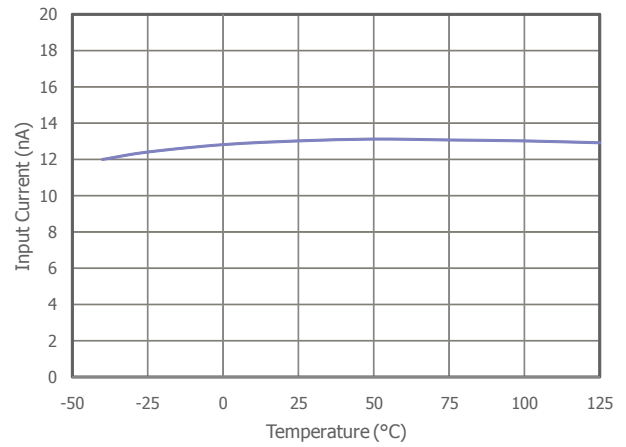
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $+V_S = 30\text{V}$, $-V_S = \text{GND}$, $R_f = R_g = 2\text{k}\Omega$, $R_L = 2\text{k}\Omega$, $G = 2$; unless otherwise noted.

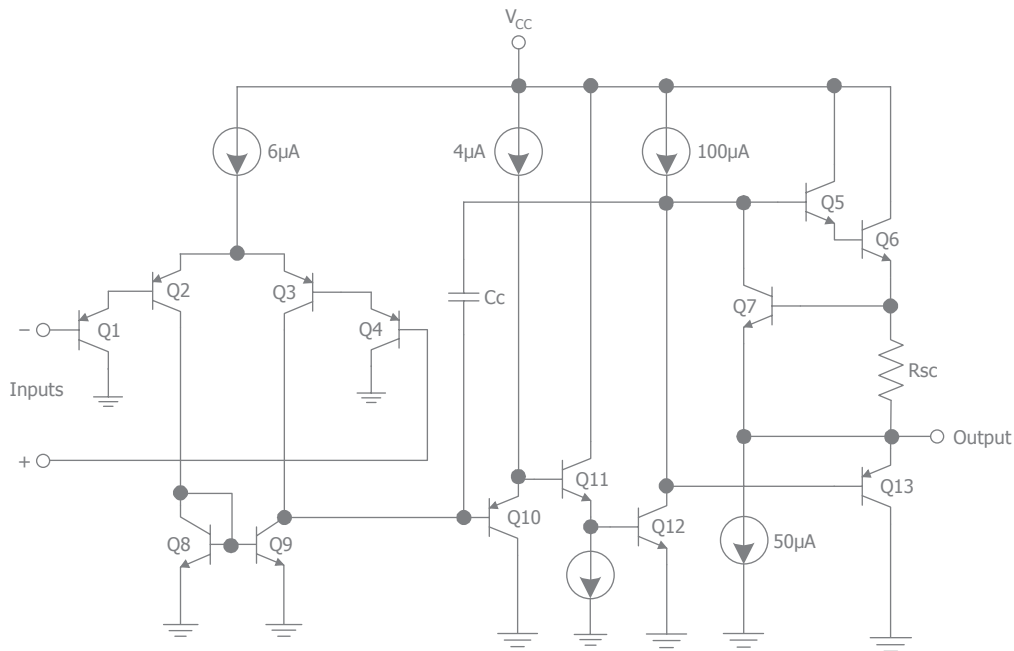
Voltage Gain vs. Supply Voltage



Input Current vs. Temperature



Functional Block Diagram





Application Information

Basic Operation

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations.

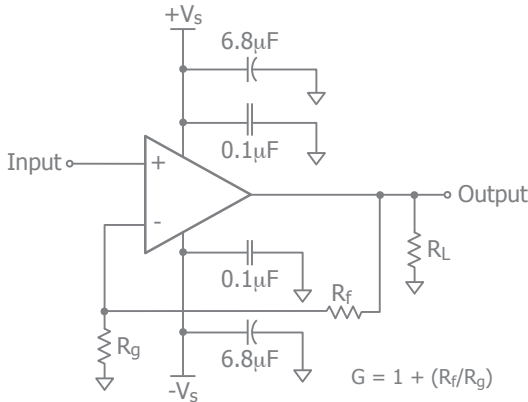


Figure 1. Typical Non-Inverting Gain Circuit

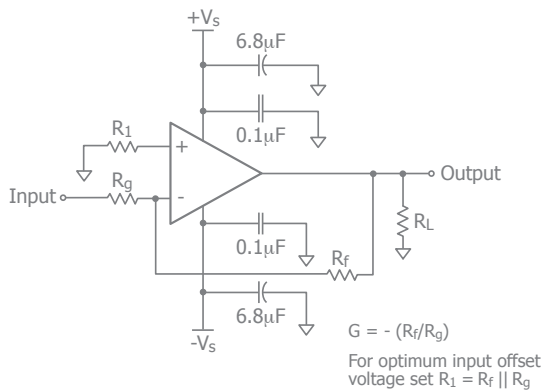


Figure 2. Typical Inverting Gain Circuit

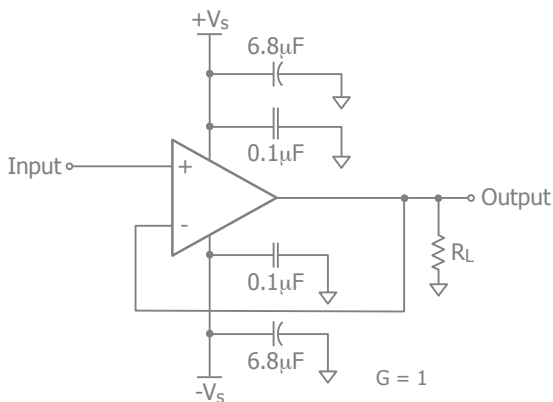


Figure 3. Unity Gain Circuit

Power Dissipation

Power dissipation should not be a factor when operating under the stated 2k ohm load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond its intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Θ_{JA} (Θ_{JA}) is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} + (\Theta_{JA} \times P_D)$$

Where $T_{Ambient}$ is the temperature of the working environment.

In order to determine P_D , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{supply} - P_{load}$$

Supply power is calculated by the standard power equation.

$$P_{supply} = V_{supply} \times I_{RMS\ supply}$$

$$V_{supply} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{LOAD})_{RMS}^2) / R_{load\ eff}$$

The effective load resistor ($R_{load\ eff}$) will need to include the effect of the feedback network. For instance,

$R_{load\ eff}$ in figure 3 would be calculated as:

$$R_L \parallel (R_f + R_g)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here, P_D can be found from

$$P_D = P_{Quiescent} + P_{Dynamic} - P_{Load}$$

Quiescent power can be derived from the specified I_S values along with known supply voltage, V_{Supply} . Load power can be calculated as above with the desired signal amplitudes using:



$$(V_{LOAD})_{RMS} = V_{PEAK} / \sqrt{2}$$

$$(I_{LOAD})_{RMS} = (V_{LOAD})_{RMS} / R_{load\,eff}$$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{DYNAMIC} = (V_{S+} - V_{LOAD})_{RMS} \times (I_{LOAD})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or $V_{supply}/2$.

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

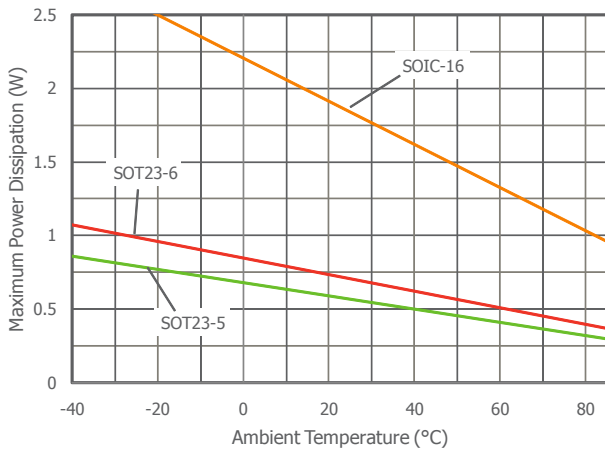


Figure 4. Maximum Power Derating

Driving Capacitive Loads

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance, R_S , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 5.

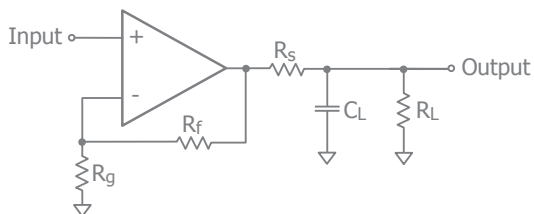


Figure 5. Addition of R_S for Driving Capacitive Loads

Table 1 provides the recommended R_S for various capacitive loads. The recommended R_S values result in ≤ 1 dB peaking in the frequency response. The Frequency Response vs. C_L plot, on page 6, illustrates the response of the CLCx050.

| C_L (pF) | R_S (Ω) | -3dB BW (kHz) |
|------------|--------------------|---------------|
| 1nF | 0 | 485 |
| 5nF | 0 | 390 |
| 10nF | 0 | 260 |
| 100 | 0 | 440 |

Table 1: Recommended R_S vs. C_L

For a given load capacitance, adjust R_S to optimize the tradeoff between settling time and bandwidth. In general, reducing R_S will increase bandwidth at the expense of additional overshoot and ringing.

Overdrive Recovery

An overdrive condition is defined as the point when either one of the inputs or the output exceed their specified voltage range. Overdrive recovery is the time needed for the amplifier to return to its normal or linear operating point. The recovery time varies, based on whether the input or output is overdriven and by how much the range is exceeded. The CLCx050 will typically recover in less than 30ns from an overdrive condition. Figure 6 shows the CLC1050 in an overdriven condition.

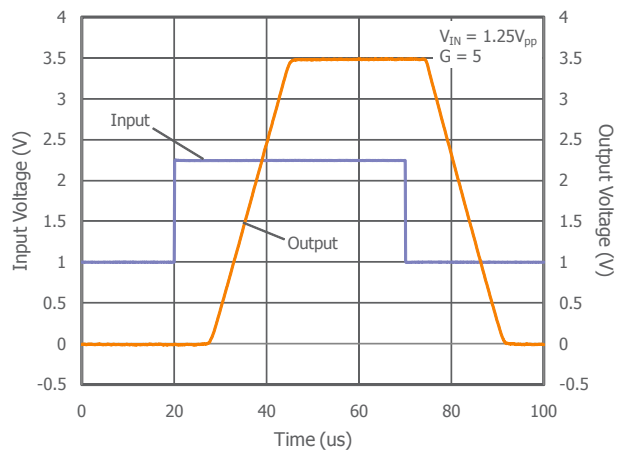


Figure 6. Overdrive Recovery



Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. CADEKA has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8 μ F and 0.1 μ F ceramic capacitors for power supply decoupling
- Place the 6.8 μ F capacitor within 0.75 inches of the power pin
- Place the 0.1 μ F capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

| Evaluation Board | Products |
|------------------|----------|
| CEB002 | CLC1050 |
| CEB006 | CLC2050 |
| CEB018 | CLC4050 |

Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 7-14. These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

1. Short -Vs to ground.
2. Use C3 and C4, if the -Vs pin of the amplifier is not directly connected to the ground plane.

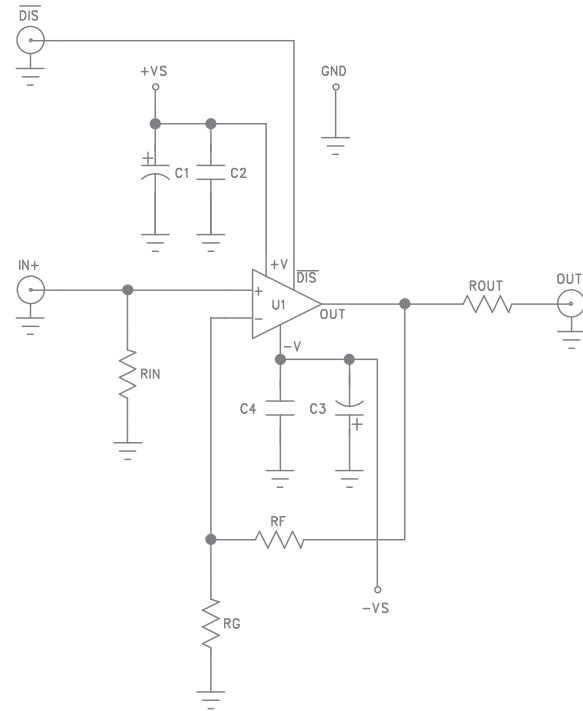


Figure 7. CEB002 Schematic

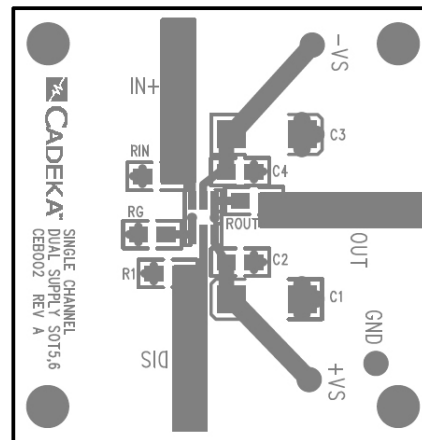


Figure 8. CEB002 Top View

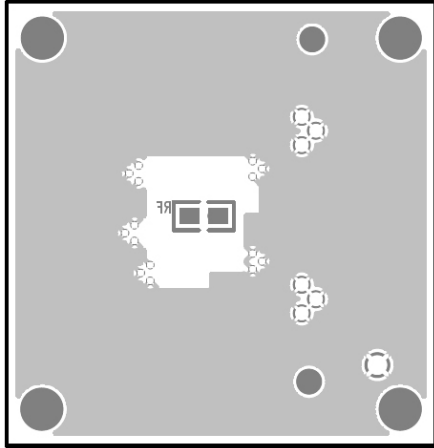


Figure 9. CEB002 Bottom View

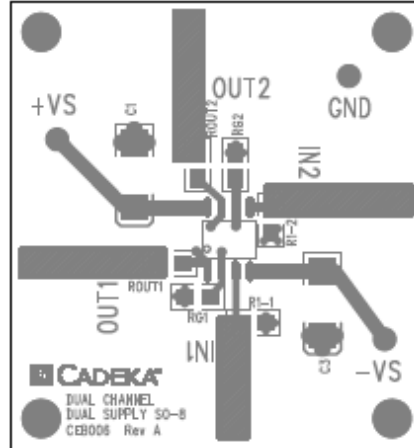


Figure 11. CEB006 Top View

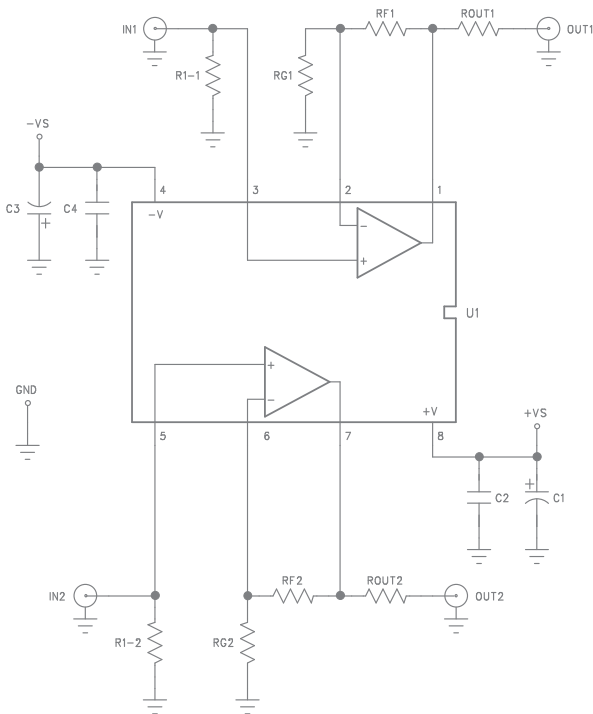


Figure 10. CEB006 Schematic

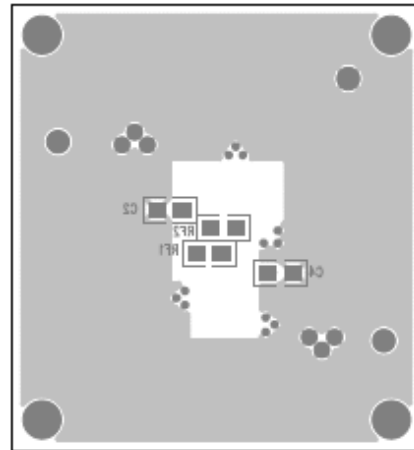


Figure 12. CEB006 Bottom View

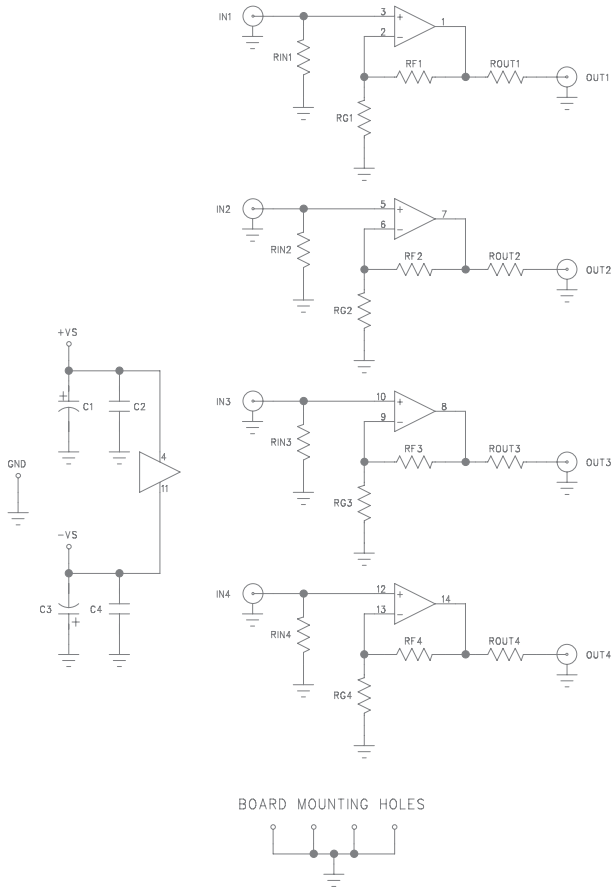


Figure 13. CEB018 Schematic

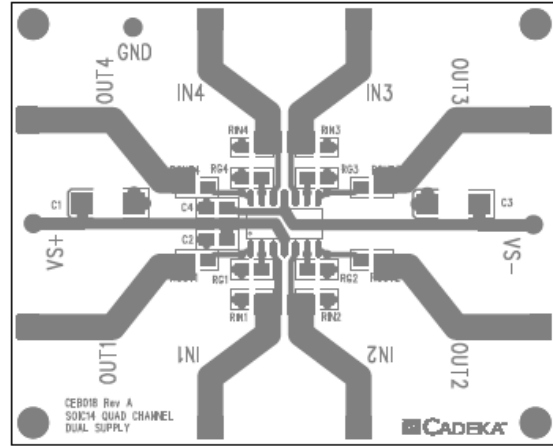


Figure 14 CEB018 Top View

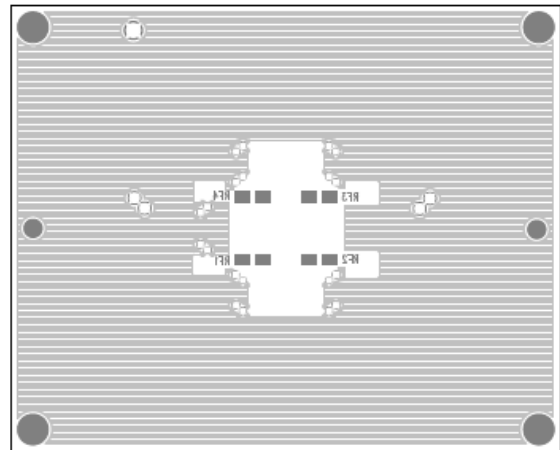


Figure 15. CEB018 Bottom View

Typical Applications

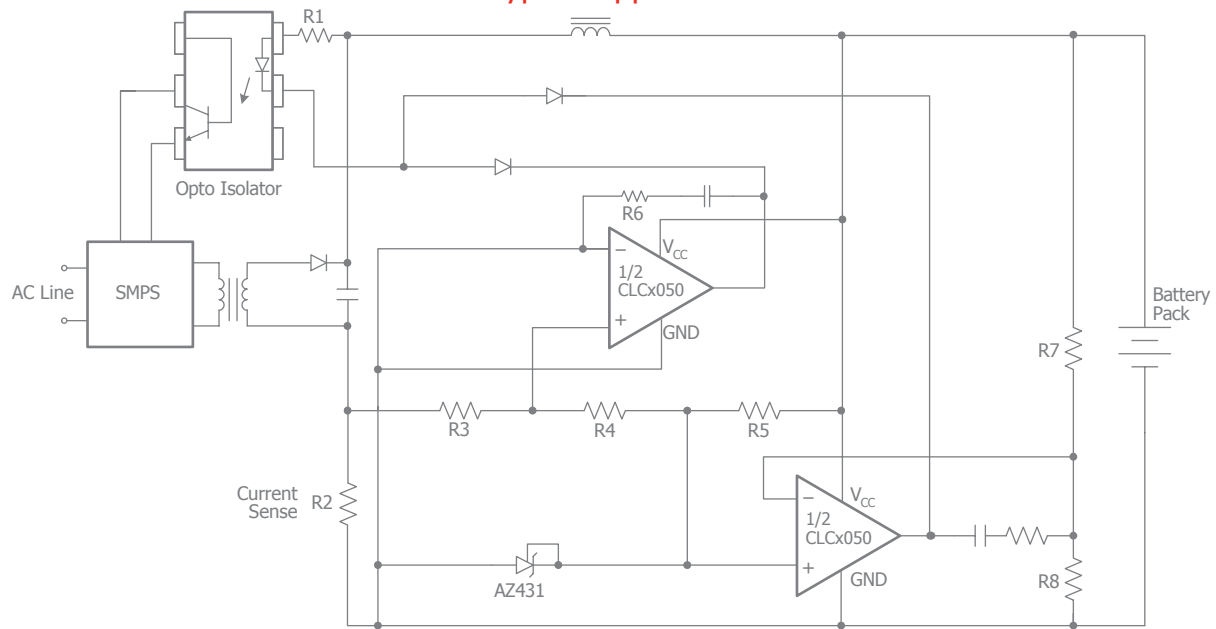


Figure 16. Battery Charger

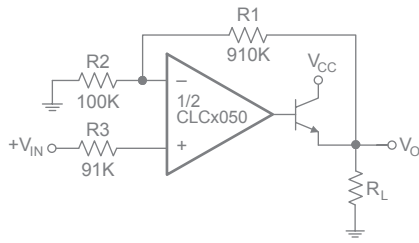


Figure 17. Power Amplifier

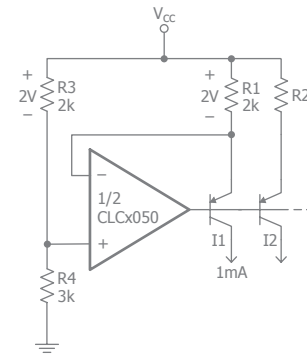


Figure 20. Fixed Current Sources

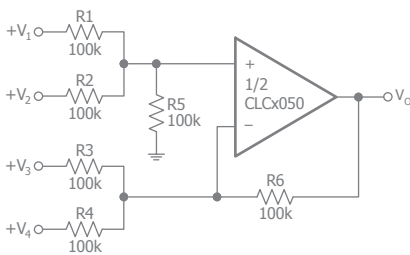


Figure 18. DC Summing Amplifier

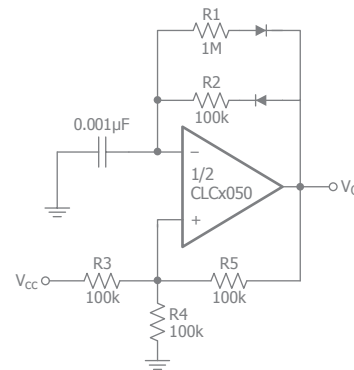


Figure 21. Pulse Generator

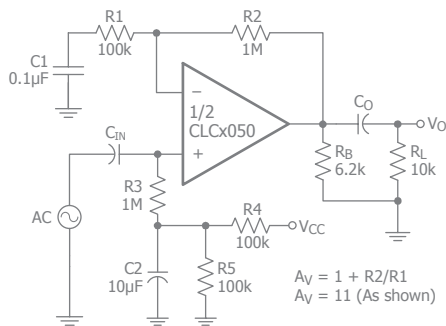


Figure 19. AC-Coupled Non-Inverting Amplifier

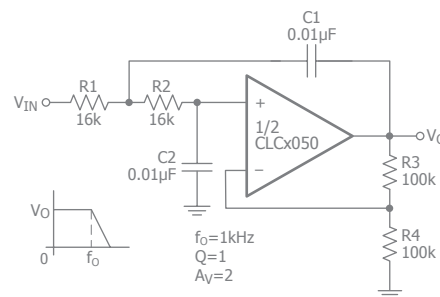
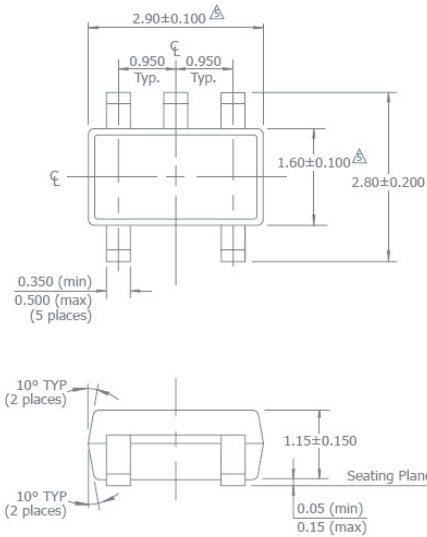


Figure 22. DC-Coupled Low-Pass Active Filter



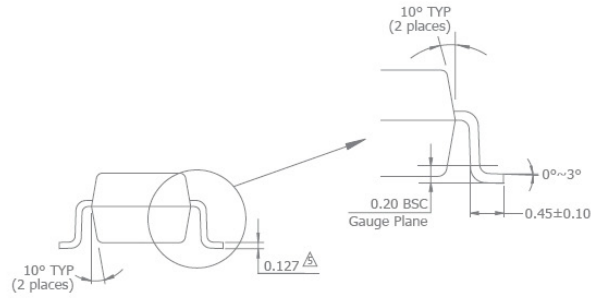
Mechanical Dimensions

SOT23-5 Package

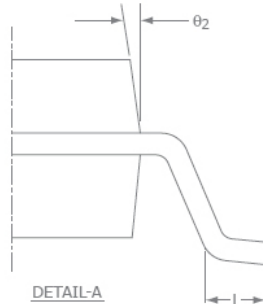
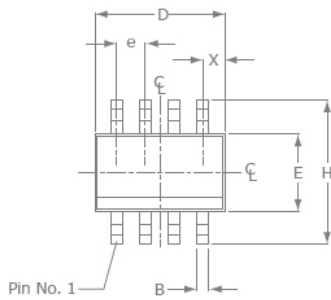


NOTES:

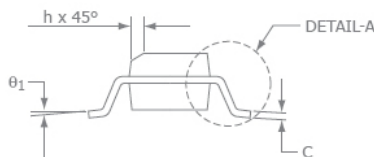
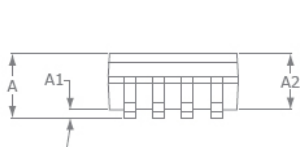
1. Dimensions and tolerances are as per ANSI Y14.5M-1982.
 2. Package surface to be matte finish VDI 11~13.
 3. Die is facing up for mold. Die is facing down for trim/form, ie. reverse trim/form.
 4. The footlength measuring is based on the gauge plane method.
- △ Dimension are exclusive of mold flash and gate burr.
 △ Dimension are exclusive of solder plating.



SOIC-8 Package



| SOIC-8 | | |
|--------|----------|------|
| SYMBOL | MIN | MAX |
| A1 | 0.10 | 0.25 |
| B | 0.36 | 0.48 |
| C | 0.19 | 0.25 |
| D | 4.80 | 4.98 |
| E | 3.81 | 3.99 |
| e | 1.27 BSC | |
| H | 5.80 | 6.20 |
| h | 0.25 | 0.5 |
| L | 0.41 | 1.27 |
| A | 1.37 | 1.73 |
| θ1 | 0° | 8° |
| X | 0.55 ref | |
| θ2 | 7° BSC | |



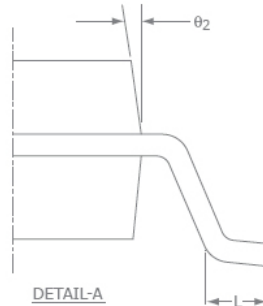
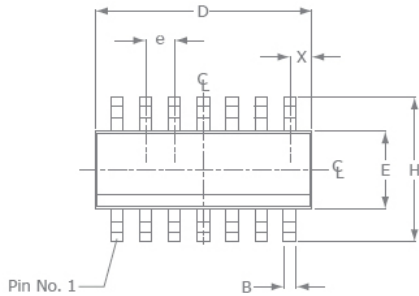
NOTE:

1. All dimensions are in millimeters.
2. Lead coplanarity should be 0 to 0.1mm (0.004") max.
3. Package surface finishing: VDI 24~27
4. All dimension excluding mold flashes.
5. The lead width, B to be determined at 0.1905mm from the lead tip.

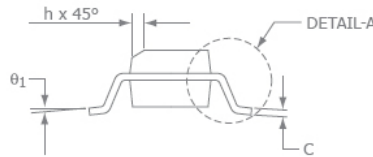
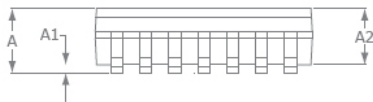


Mechanical Dimensions continued

SOIC-14 Package



| SOIC-14 | | |
|------------|----------|------|
| SYMBOL | MIN | MAX |
| A1 | 0.10 | 0.25 |
| B | 0.36 | 0.48 |
| C | 0.19 | 0.25 |
| D | 8.56 | 8.74 |
| E | 3.84 | 3.99 |
| e | 1.27 BSC | |
| H | 5.80 | 6.20 |
| h | 0.25 | 0.5 |
| L | 0.41 | 1.27 |
| A | 1.37 | 1.73 |
| θ_1 | 0° | 8° |
| X | 0.51 ref | |
| θ_2 | 7° BSC | |



NOTE:

1. All dimensions are in millimeters.
2. Lead coplanarity should be 0 to 0.1mm (0.004") max
3. Package surface finishing: VDI 24~27
4. All dimension excluding mold flashes.
5. The lead width, B to be determined at 0.1905mm from the lead tip.

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CADEKA Headquarters Loveland, Colorado
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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

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